NSN 5961-01-212-8070

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-212-8070 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Terminal Length:** 0.250 inches **Overall Height:** 0.185 inches **Overall Width:** 0.310 inches **Component Name And Quantity:** 13 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 40.0 working peak reverse voltage all semiconductor device diode **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Common cathode; all semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No